

A 16-Bit, Low-Power Microsystem with Monolithic MEMS-LC Clocking

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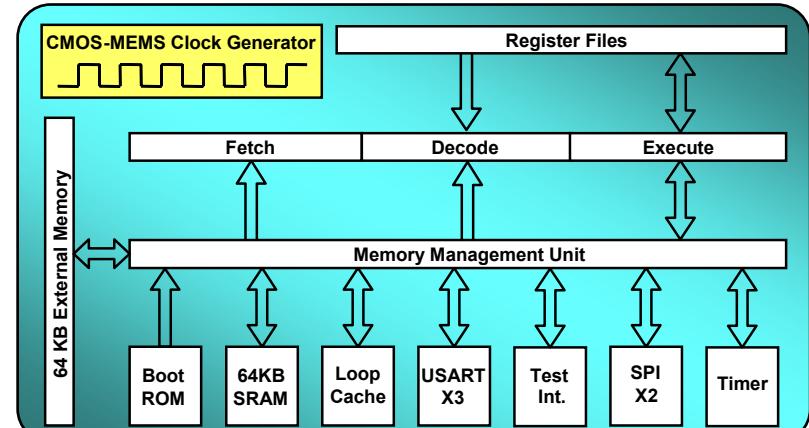
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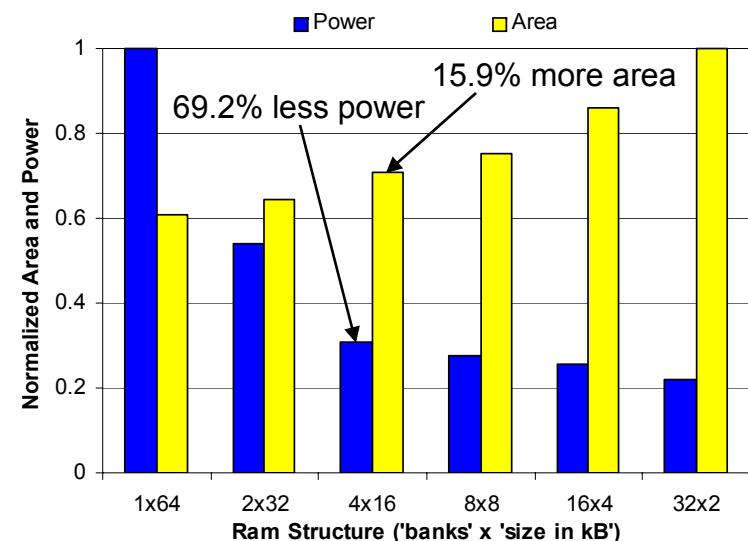
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Microsystem Architecture

- 16/24-bit, 3-stage pipeline
- Load-Store architecture
- 77 instructions, 8 address modes
- Windowed registers
- Hardware support for one level of interrupts and subroutines
- 4x16KB banked memory architecture with external memory interface
- Peripheral interfaces
- 512B loop cache
- Register controlled clock interface
- Low latency, glitch-free dynamic frequency scaling



Microsystem architecture



SRAM energy/area tradeoffs



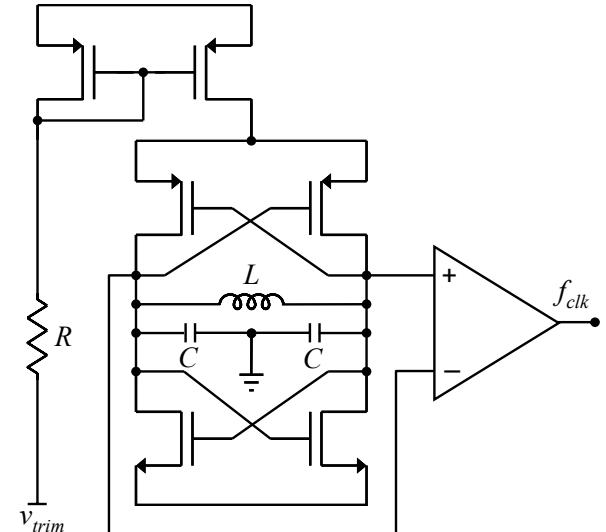
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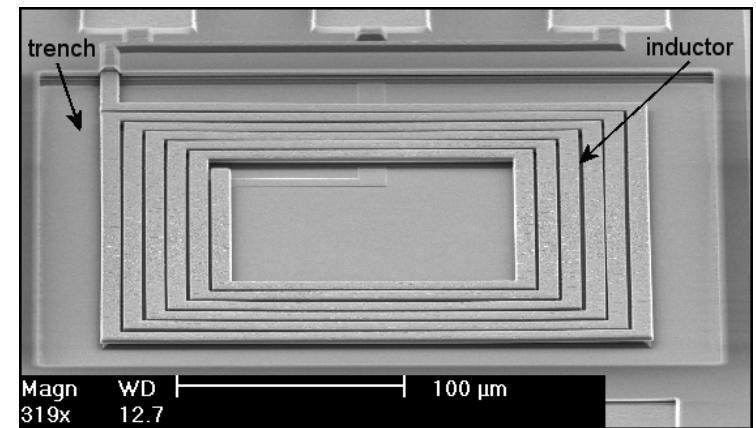
Monolithic Clock Generation

- Complementary, cross coupled, negative-transconductance tank
- CMOS compatible suspended inductor
 - Post processing etch using PAD cut
- Frequency trimming via modulation of tail current v_{trim}
- High frequency accuracy so no external reference or DLL/PLL

Metric/Parameter	LC Clock
Reference frequency	1056MHz
Frequency precision (no trim)	$\pm 2\%$
Trimmed frequency accuracy	100ppm
Worst case duty cycle	48/52
Worst case RMS period jitter	<300ppm
Temperature stability (-40 to 100C)	$\pm 0.9\%$
Power dissipation	17.28mW
Start-up latency (25C/125C)	18ns/28ns



LC tank schematic



Suspended inductor

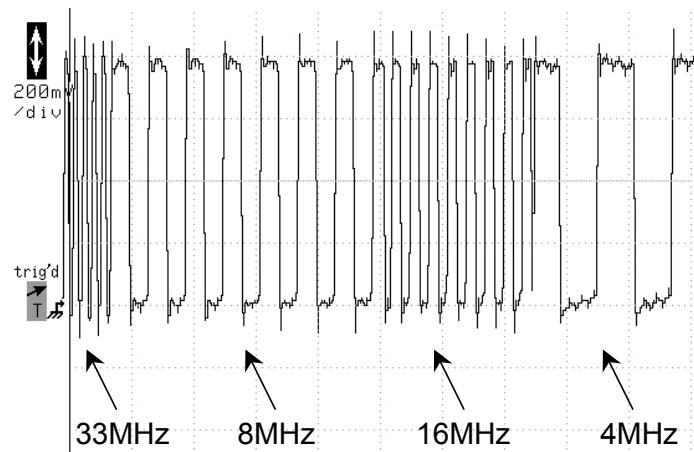
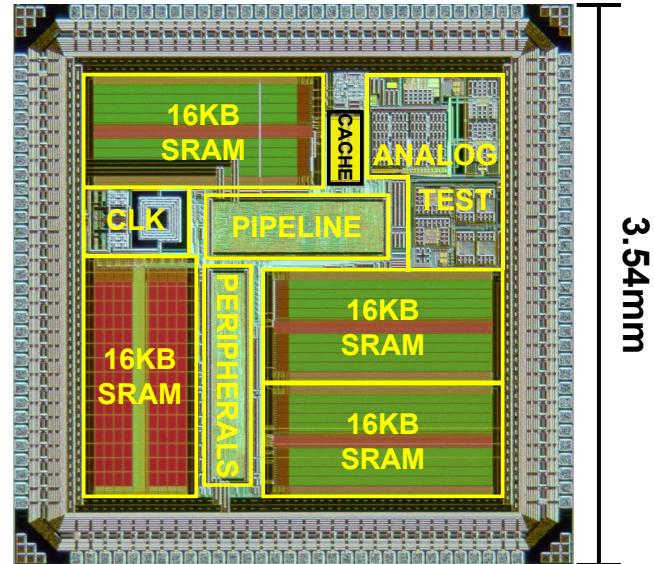


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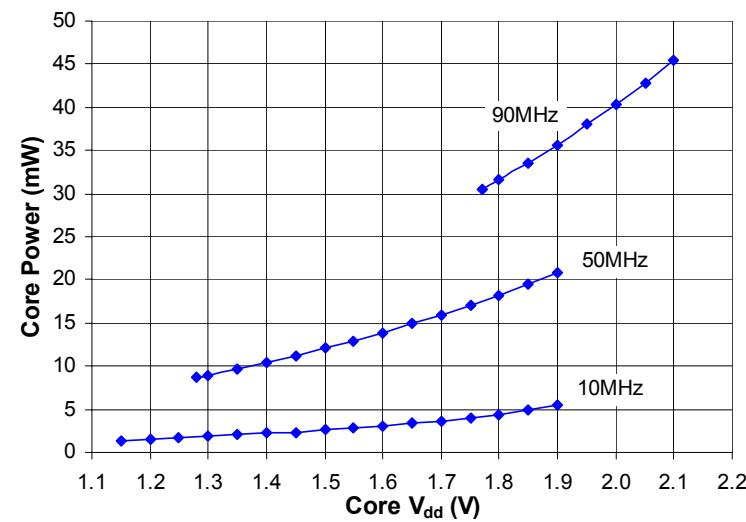


Microsystem Measured Results

- TSMC 0.18 μ m MM/RF bulk CMOS
- 3.5 million transistors
- 33.9mW core power @ 92MHz & 1.8V
- 1.4mW core power @ 10MHz & 1.1V
- 740 μ W sleep power @ 1.1V
- Static loop cache utilization provides 4 to 20% energy savings



Low latency (37.45ns), glitch-free dynamic clock frequency scaling



Measured power as V_{dd} is scaled for 10, 50, and 90MHz



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Conclusion

- **Highly-functional, low-power microsystem for remote and bio-medical applications**
- **Dynamic frequency scaling**
 - 33.9mW @ 90MHz
 - 1.4mW @ 10MHz
 - 740 μ W in sleep mode
- **Monolithic clock reference decreases system size, cost, and power dissipation**
- **Power-aware compiler leverages custom ISA, loop cache, register windows**

	This Work	Berkeley SmartDust	TI MSP-430F21x1	National CP3000	AMD AM186ER	ARM922T
Maximum Frequency	92MHz	0.5MHz	16MHz	24MHz	50MHz	250MHz
Active Current	188 μ A / MHz	11.8 μ A / MHz (logic only)	200 μ A / MHz	500 μ A / MHz	3900 μ A / MHz	250 μ A / MHz
Power Supply	1.8V	1.0V	1.8 - 3.6V	2.5V	3.3V	1.2V
Program Memory	64kB SRAM	2.2kB SRAM	8kB Flash	256kB Flash	32kB SRAM	8kB SRAM (cache)
Data Memory		1kB SRAM	256b SRAM	10kB SRAM		8kB SRAM (cache)
Instruction / Data Width	16 / 16-bit	17 / 8-bit	16 / 16-bit	16 / 16-bit	16 / 16-bit	16 (Thumb) / 32-bit
Peripherals	Timer, USART, SPI, GPIO	Timer	Timer, UART	USB, CAN, USART, SPI, GPIO, Timer, Bluetooth	Timer, USART, UART	-

